

RoHS Compliant Product
A suffix of "C" specifies halogen free

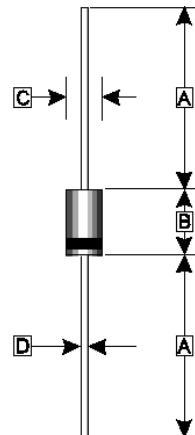
FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop
- Low reverse current
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Weight: 1.1 g (Approximate)

DO-27(DO-201)



REF.	Millimeter	
	Min.	Max.
A	25.4 (TYP)	
B	7.20	9.50
C	4.80	5.60
D	1.10	1.30

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, de-rate current by 20%).

Parameter	Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	120	V
Working Peak Reverse Voltage	V _{RSM}	120	V
Maximum DC Blocking Voltage	V _{DC}	120	V
Maximum Average Forward Rectified Current	I _F	5	A
Peak Forward Surge Current, 8.3 ms single half sine-wave	I _{FSM}	150	A
Voltage Rate of Change (Rated V _R)	dv/dt	10000	V / μ s
Typical Thermal Resistance	R _{θJC}	12	°C / W
Operating and Storage Temperature Range	T _J , T _{STG}	-40~150	°C

ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Typ.	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V _F	0.65	0.7	V	I _F = 3A, T _A = 25°C
		0.70	0.75		I _F = 5A, T _A = 25°C
		0.56	-		I _F = 5 A, T _A = 125°C
Maximum DC Reverse Current at Rated DC Blocking Voltage ²	I _R	-	0.1	mA	T _A =25°C
		-	10		T _A =100°C
Typical Junction Capacitance ¹	C _J	210	-	pF	

NOTES:

1. Measured at 1MHz and applied reverse voltage of 5.0V D.C.
2. Pulse Test : Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

RATINGS AND CHARACTERISTIC CURVES

